

# NOT RECOMMENDED FOR NEW DESIGN USE HBS410



TT410

#### **4A SURFACE MOUNT GLASS PASSIVATED BRIDGE RECTIFIER**

#### Product Summary (@TA = +25°C)

V <sub>RRM</sub> (V)	I <sub>O</sub> (A)	V <sub>F</sub> (V)	I <sub>R</sub> (μ <b>A</b> )
1000	4	1.0	5

### **Features and Benefits**

- Glass Passivated Die Construction
- Compact, Thin Profile Package Design
- Low Forward Voltage Drop Improves Power Efficiency
- · High Current and Surge Capability
- Reliable Robust Construction
- Ideal for SMT Manufacturing
- Rated at 1000V PRV
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

### **Description and Applications**

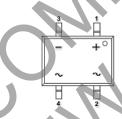
Suitable for AC to DC bridge full wave rectification for SMPS, LED lighting, adapter, battery charger, home appliances, office equipment, and telecommunication applications.

#### **Mechanical Data**

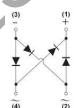
- Case: TT
- Case Material: Molded Plastic.
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Lead Free Plating (Matte Tin Finish). Solderable per MIL-STD-202, Method 208 (3)
- Polarity: As Marked on Body
- Weight: 0.297 grams (Approximate)



Top View



Pin Diagram



Internal Schematic

### Ordering Information (Note 4)

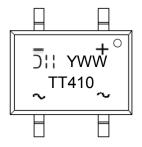
Part Number	Compliance	Case	Packaging
TT410-13	Commercial	TT	1,500/Tape & Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and
- <1000ppm antimony compounds.

  4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

### **Marking Information**



TT410= Product Type Marking Code

| I = Manufacturers' Code Marking

| YWW = Date Code Marking
| Y = Last Digit of Year (ex: 7 = 2017)

| WW = Week Code (01 to 53)



### **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	1,000	V
RMS Reverse Voltage	V <sub>R(RMS)</sub>	700	V
Average Rectified Output Current (Note 5) @ T <sub>A</sub> = +25°C	Io	4.0	Α
Non-Repetitive Peak Forward Surge Current, 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I <sub>FSM</sub>	120	Α
Non-Repetitive Peak Forward Surge Current, 1.0ms Single Half Sine-Wave Superimposed on Rated Load	I <sub>FSM</sub>	240	Α
I <sup>2</sup> t Rating for Fusing (1ms < t < 8.3ms)	I <sup>2</sup> t	59	A <sup>2</sup> S

### **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Typical Thermal Resistance, Junction to Ambient (Note 5) (Per Element)	R <sub>0</sub> JA	13	°C/W
Typical Thermal Resistance, Junction to Lead (Per Element)	R <sub>0</sub> JL	8	°C/W
Typical Thermal Resistance, Junction to Case (Per Element)		3	°C/W
Operating and Storage Temperature Range	$T_{J_s}T_{STG}$	-55 to +150	°C

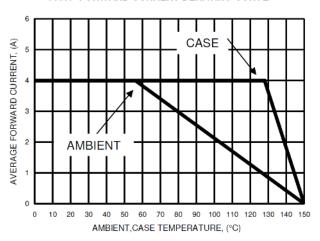
### Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 6)	V <sub>(BR)R</sub>	1,000	1	1	V	I <sub>R</sub> = 10μA
Forward Voltage (Per Element)	V		0.91	1.0	V	I <sub>F</sub> = 2A, T <sub>A</sub> = +25°C I <sub>F</sub> =2A, T <sub>A</sub> = +125°C
Forward Voltage (Fer Element)	VF	_	0.80	1	V	I <sub>F</sub> =2A, T <sub>A</sub> = +125°C
Leakage Current (Note 6) (Per Element)			0.15	5	μA	V <sub>R</sub> = 1,000V, T <sub>A</sub> = +25°C
Leakage Current (Note of (Fer Element)	IR	_	55	500	μΑ	V <sub>R</sub> = 1,000V, T <sub>A</sub> = +125°C
Total Capacitance (Per Element)	Ст	_	40	_	pF	V <sub>R</sub> = 4V, f = 1.0MHz

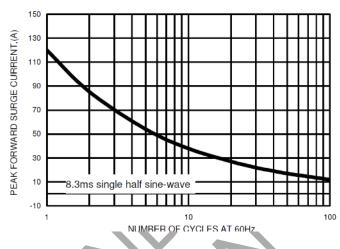
5. Device mounted on 15mmx12mmx1.6mm AL Pad attached on 100mmx75mmx27mm Fin heatsink. Thermal resistance test performed in accordance with JESD-51.
6. Short duration pulse test used to minimize self-heating effect.



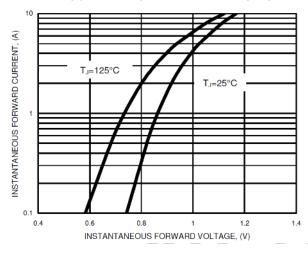
#### FIG.1- FORWARD CURRENT DERATING CURVE



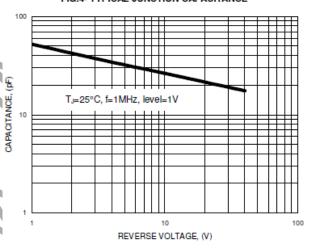
#### FIG.2- MAXIMUM NON-REPETITIVE SURGE CURRENT



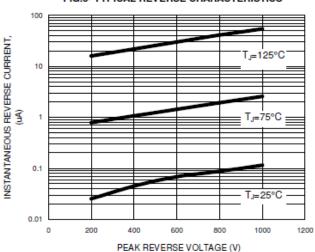
#### FIG.3- TYPICAL FORWARD CHARACTERISTICS



#### FIG.4- TYPICAL JUNCTION CAPACITANCE



#### FIG.5- TYPICAL REVERSE CHARACTERISTICS

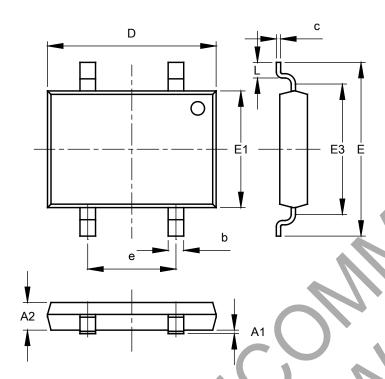




### **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

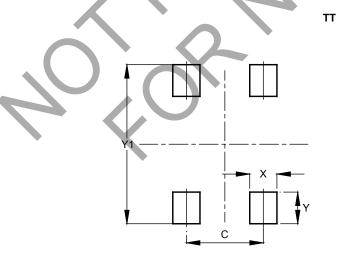
TT



TI						
Dim	Min	Max	TYP			
A1	0.10	0.20				
A2	1.40	1.60	1			
b	0.70	0.90	-			
С	0.15	0.35	1			
D	9.45	9.75	-			
Е	9.75	10.05	-			
E1	6.30	6.75	7			
E3	7.85	8.15				
е	4.90	5.10				
L	0.45	0.95				
All Dimensions in mm						

## Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)		
С	5.00		
Х	1.80		
Υ	2.10		
Y1	11.70		



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